

2000

A Survey of Methodologies for the Hardware Reliability Prediction of Electronic Equipment

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가

ML-HDBK-217

Bellcore TR-332

Abstract

Digital I&C systems are being used widely in the non-safety systems of the NPP and they are expanding their applications to safety critical systems. The regulatory body shifts their policy to risk based and may require Probabilistic Safety Assessment for the digital I&C systems. But there is no established reliability prediction methodology for the digital I&C systems including both software and hardware yet. This survey includes a lot of reliability prediction methods for electronic equipment in view of hardware. Each method has both the strong and the weak points. This report provides the state-of-art of prediction methods and focus on Bellcore TR-332 method and ML-HDBK-217 method extensively.

1.

[1]

가

가 가

가

[2]

가

2.

Reliability Analysis Center

1 [3]



1

9 %

60%

2.1

가

가 가

- ML-HDBK-217 (revision F) [4]
- HRD4 [5]
- Siemens (SN29500) [6]
- CNET [7]
- Bellcore (TR-TSY-000332, issue 6) [8]
- Italtel IRPH93 [9]
- NIT [10]

가 가

ML-HDBK-217

Rome

(Reliability Analysis Center: RAC)

Bellcore

TR-332

Bellcore

ML-HDBK-217

1985

Bellcore

HRD(), Siemens(), NIT(), Italtel(), CNET()

가

가

ML-HDBK-217

Bellcore

TR-332

2.2 ML-HDBK-217

ML-HDBK-217

가

가

ML-HDBK-217

가

가

ML-HDBK-217F

(part stress analysis)

(part count analysis)

가

가

가

가

가

(conservative estimate),

ML-HDBK-217F

19 84

() (default value)

2.2.1

LSI, MSI, SSI
 (lead)
 TIL, LIN, MOS
 가 가 가

()

(λ_p)

$$\lambda_p = \lambda_b \pi_E \pi_A \pi_Q \pi_T \cdots \pi_n$$

λ_b :

π_Q :

π_E :

π_n :

π_A :

π_T :

2.2.2

가
 가
 가
 ML-HDBK-217F (issue 2)
 (generic failure rate)
 가

$$\lambda_{EQUIP} = \sum_{i=1}^n N_i (\lambda_g \pi_Q)_i$$

λ_{EQUIP} : (/ 10^6)
 λ_g : i (/ 10^6)
 π_Q : i
 N_j : i
n :

가 가 “ - ”

λ_g π_L
2
($\pi_L=1$). 2
가
가
가
() λ_g

2.3 Bellcore TR-332

Bellcore ML-HDBK-217 가 Bellcore TR-332
6 Bellcore 3가
- I :
- II : burn-in
- III :
Bellcore II, III
I Bellcore
가

, ML-HDBK-217,

2.3.1 I :

ML-HDBK-217

()

burn-in 3가

- 1 : 40 가 50% 가 burn-in

- 2 : 40 가 50% 가 burn-in

- 3 : 가 (가 40

가 50%)

1 가 3 가

가 2 1 burn-in

, burn-in

3

(1)

3

$$\lambda_{SS_i} = \lambda_{G_i} \pi_{Q_i} \pi_{S_i} \pi_{T_i}$$

$\lambda_{G_i} : i$

$\pi_{Q_i} : i$

$\pi_{S_i} : i$

$\pi_{T_i} : i$ ()

ML-HDBK-217 , Bellcore

(TR-332 Table 11)

1 가 3 가

가 2 1 burn-in

, burn-in

3

3

$$\lambda_{SS_i} = \lambda_{G_i} \pi_{Q_i} \pi_{S_i} \pi_{T_i}$$

$\lambda_{G_i} : i$

$\pi_{Q_i} : i$

$\pi_{S_i} : i$
 $\pi_{T_i} : i$ () .

ML-HDBK-217 , Bellcore
 (TR-332 Table 11) . Bellcore

16 .

가 40 가 50% 1, 2 $\pi_T = \pi_S = 1.0$

$$\lambda_{SS_i} = \lambda_{G_i} \pi_{Q_i}$$

$$\lambda_{SS} = \pi_E \sum_{i=1}^n N_i \lambda_{SS_i}$$

n =

$N_i = i$

$\pi_E =$.

ML-HDBK-217

$$\lambda_{HIC} = \sum (\lambda_G \pi_Q \pi_S \pi_T) + (N_I \lambda_I N_C \lambda_C N_R \lambda_R) (\pi_F)$$

2.3.2 II :

II

가

(laboratory test)

가 I

II

가

가

TR-332

A

$\lambda_{SS} / (\pi_E \pi_T)$

가

II

II

II

(device)

(unit)

II

A

II

III . II A 가 , II
 가 . A 가 I

II 4가
 - L1 : burn-in
 - L2 : / burn-in
 - L3 : burn-in
 - L4 : / burn-in
 II (λ_{G_i})

n =
 $\lambda_{G_i} = \text{TR- 332}$ [FITS]
 $N_0 =$ /
 $T_1 =$
 $\pi_Q =$
 $\lambda_G =$ ($\lambda_{SS} / (\pi_E \pi_T)$)
 $\lambda_{G_i}^* =$
 $\lambda_G^* =$

4가 3
 (1) burn-in
 $T_e = A_{b,d} t_{b,d}$
 $A_{b,d} =$ burn-in 가 (G 7)
 $t_{b,d} =$ burn-in ()

(2) II ($\lambda_{G_i}^*$)
 $\lambda_{G_i}^* = [2 + n] / [(2 / \lambda_{G_i}) + (4 \times 10^{-6}) N_0 W \pi_Q]$

(3) W
 $T_1 + T_e \leq 10,000$
 $W = (T_1 + T_e)^{0.25} - T_e^{0.25}$
 $T_1 + T_e > 10,000 \geq T_e$
 $W = ((T_1 + T_e)4000) + 7.5 - T_e^{0.25}$
 $T_e > 10,000$
 $W = T_1/4$

$$(4) \quad \text{II} \quad \text{I} \quad \lambda_{G_i}$$

$$\lambda_{SS_i} = \lambda_{G_i}^* \pi_{Q_i} \pi_{S_i} \pi_{T_i} \quad (3)$$

$$\lambda_{SS_i} = \lambda_{G_i}^* \pi_{Q_i} \quad (1, 2)$$

2.3.3 III :

III

- :

- :

- : 가 가

- :

가

III

$t =$

$f = t$

$\phi =$

$\phi' = \left(\frac{f}{t} \right) \text{ [FITs]}$

$N_i = i$

$\lambda_{SS_1} = \text{I}$

$\lambda_{SS_1} = \lambda_{SS} \quad \text{--}$

$\lambda_{SS_1} = \lambda_{SS_i} \pi_E \quad \text{--}$

$\lambda_{SS_2} = \text{I}, \quad 3$

$\lambda_{SS_2} = \lambda_{SS}$

$\Theta_{SS_i} = \text{III} \quad i$

$\Theta_{SS} = \text{III}$

$\Theta_{SS_3} = \text{III}$

$\pi_{T_1}, \pi_{T_2} = \quad (1) \quad (2)$

(TR-332, 11-7)

III

3가

- III(a) :

- III(b) :

- III(c) :

III

가

Ground benign, Ground fixed, Ground mobile)

3000

III

t

(1)

1

III(a) III(b)	$t \geq \frac{2 \times 10^9}{\lambda_{SS_1}}$
III(C)	$t \geq \frac{2 \times 10^9}{\lambda_{SS_2}}$

III

(1)

f

t

(2)

III(b)

III(C)

(1),

(2)

π_{T_1}, π_{T_2}

(3)

가

λ_{SS_1}

- III(a) III(b) :

I ,

1

3

λ_{SS_1}

- III(C) :

I ,

3

λ_{SS_1}

(4)

가

I

λ_{SS_2}

(5)

(2)

V =	1.0	III(a)
	$\frac{\pi_{T_2}}{\pi_{T_1}}$	III(b)
	$\frac{\lambda_{SS_2}}{\lambda_{SS_1}}$	III(c)

(6) III (3)

3 III

λ_{SS_1}	$\Theta_{SS_3} = \frac{2+f}{\frac{2}{\lambda_{SS_1}} + (V \times t \times 10^9)}$
λ_{SS_1} (III(a) III(c))	$\Theta_{SS_3} = \frac{10^9 \times U}{t \times V}$

U f Poisson 95%

Bellcore

$$\lambda_{SYS} = \sum_{j=1}^M \lambda_{SS(j)}$$

$\lambda_{SS(j)}$ j , M

$$\pi_{FYSYS} = \frac{\sum_{j=1}^M \lambda_{SS(j)} \pi_{FY(j)}}{\lambda_{SYS}}$$

$\pi_{FY(j)}$ j

3.

ML-HDBK-217 Bellcore TR-332

가

$$\lambda_{PART_i} = \lambda_{G_i} \sum_{i=1}^n \pi_{F_i}$$

$$\lambda_{EQIP} = \pi_E \sum_{i=1}^n N_i \lambda_{PART_i}$$

가

4

Bellcore	Electrical stress
CNET	Quality
HRD4	Quality
ML-HDBK-217	Environment, Quality
Siemens	Temperature

가

가

64K DRAM

5

[12]

5 64K DRAM

	[FIT]	
	1986	1994
ML-HDBK-217D/F	11250	49
HRD 3/4	10	8
CNET	541	22
NIT	542	14
Bellcore TR-332	550	45

8

가

“(learning factor)”

가

가

6

() 가

9

7 [11]

(The

International Electronic Reliability Institute)

가

ML-HDBK-217 Bellcore

(MBF)

ML-HDBK-217 Bellcore

Bellcore 가

Bellcore

(MBF)

	ML-HDBK-217 (FIT/ 1000)	(FIT/ 1000)
A	400	19607
B	400	460
C	800	2119
D	138	862
E	173	13513
F	500	947
G	286	1600
H	625	277
I	714	10200

7 CB #1

(=no/FIT)

Device	Bellcore	CNET	HRD4	ML217	Siemens
ceramic multilayer capacitor	210	45	3	4	35
pn_junctiondiode	125	300	300	9	25
Bipolar digital IC	936	390	168	50	60
Metal oxide resistor	1590	596	51	52	795
Discrete bipolar transistor	7812	20937	4000	1225	1250
Tantalum electrolytic capacitor	1350	3780	40	594	180
TOTAL failure rate	12023	26048	4562	1934	2345
Field failure rate	4274				
Deviation	7749	21774	288	-2340	-1929

Bellcore (basic failure rate) ML-HDBK-217

ML-HDBK-217 Bellcore TR-332 [13]

(1) Bellcore 3 ML-HDBK-217
147가

ML-HDBK-217

(2) Bellcore (ambient temperature)

ML-HDBK-217

Bellcore

(3) Bellcore SMT(smalltalk)

SMT

ML-HDBK-217 SMT 가 SMT 가

(4) Bellcore

ML-HDBK-217

(5) Bellcore

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